

TPN3021

Tripolar overvoltage protection for network interfaces

Features

- Triple crowbar protection
- Low capacitance
- Low holding current: I_H = 30 mA minimum
- Surge current:
 - I_{PP} = 200 A, 2/10 μs
 - I_{PP} = 30 A, 10/1000 µs

Main applications

Dedicated to data line protection, this device provides a tripolar protection function. It ensures the same protection capability with the same breakdown voltage in both common and differential modes.

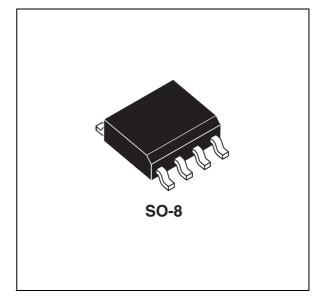
Description

The TPN3021 is a low capacitance transient surge arrestor designed for protection of high debit rate communication network. Its low capacitance avoids distorsion of the signal as it has been designed for T1/E1 and Ethernet networks.

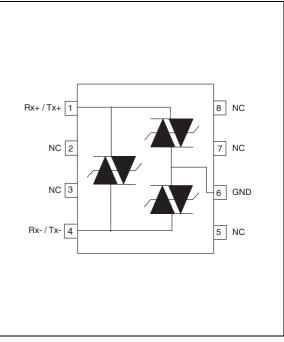
Benefits

Trisil technology is not subject to ageing and provides a fail safe mode in short circuit for a better protection. They are used to help equipment to meet main standards such as UL1950, IEC950 / CSA C22.2 and UL1459. They have UL94 V0 ap-proved resin. SO8 package is JEDEC registered.

Trisils comply with the following standards GR-1089 Core, ITU-T-K20/K21, VDE0433, VDE0878, IEC61000-4-2.



Schematic diagram



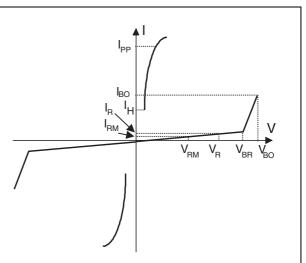
1 Characteristics

| Standard | Peak surge voltage (V) | Voltage waveform | Required peak current (A) | | |
|-------------------------------|---------------------------|------------------------|------------------------------|--------------------------|-----------|
| GR-1089 Core First level | 2500 1000 | 2/10 μs 10/1000 μs | 500 100 | 2/10 μs 10/1000 μs | 7.5 25 |
| GR-1089 Core Intrabuilding | 1500 | 2/10 µs | 100 | 2/10 µs | 0 |
| ITU-T-K20/K21 | 1000 | 10/700 µs | 25 | 5/310 µs | 0 |
| ITU-T-K20 (IEC61000-4-2) | 6000 8000 | 1/60 ns | | t discharge discharge | |
| VDE0433 | 4000 2000 | 10/700 µs | 00 μs 100 50 5/310 μs | | 40 0 |
| VDE0878 | 4000 2000 | 1.2/50 µs | 100 50 | 1/20 µs | 0 0 |
| IEC61000-4-5 | 2000 2000 | 10/700 μs 1.2/50 μs | 50 50 5/310 μs 8/20 μs | | 0 0 |

| Table 1. | Complies with the following standards |
|----------|---------------------------------------|
| | |

Table 2.Electrical characteristics (T_{amb} =25°C)

| Symbol | Parameter |
|-----------------|---------------------------|
| V _{RM} | Stand-off voltage |
| V _{BO} | Breakover voltage |
| V _{BR} | Breakdown voltage |
| I _H | Holding current |
| I _{BO} | Breakover current |
| I _{RM} | Leakage current at VRM |
| I _{PP} | Peak pulse current |
| С | Capacitance |
| V _R | Continous reverse voltage |
| ۱ _R | Leakage current at VR |



| | Absolute ratings (ramb =25 0) | | | |
|------------------------------------|---|---|---|---------|
| Symbol | Parameter | Value | Unit | |
| I _{pp} | Peak pulse pulse current: tr / tp | 10/1000 μs 8/20 μs 10/560 μs 5/310 μs 10/160 μs 1/20 μs 2/10 μs | 30 100 40 50 75 100 200 | A |
| | Non repetitive surge peak on-state current One cycle | 50 Hz 60 Hz | 8 9 | А |
| I _{TSM} | Non repetitive surge peak on-state current F=50Hz | 0.2 s 2 s | 3 1.5 | A |
| T _{stg} T _j | Storage temperature range Operating junction temperature range | | -55 to +150 -40 to +150 | °C ℃ |
| Τ _L | Maximum lead temperature for soldering during 10s | 260 | °C | |

Table 3. Absolute ratings (T_{amb} =25°C)

Repetitive peak pulse current

 t_r : rise time (µs)

 t_p : pulse duration time (µs)

example: pulse waveform

 $10/1000 \ \mu s, tr = 10 \ \mu s, tp = 1000 \ \mu s$

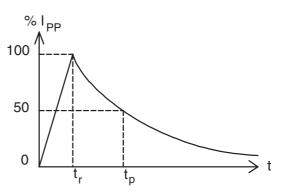


Table 4. Thermal resistances

| Symbol | Parameter | Value | Unit | |
|----------------------|---------------------|-------|------|--|
| R _{th(j-a)} | Junction to ambient | 170 | °C/W | |

Table 5.Electrical parameters ($T_{amb} = 25^{\circ}C$)

| Туре | I _{RM} @V _{RM} max. | | V _{BO} max max. | (@I _{BO} ⁽¹⁾ | l _H ⁽²⁾ min. | C ⁽³⁾ typ. |
|---------|--|----|-----------------------------|----------------------------------|---------------------------------------|--------------------------|
| | μA | V | V | mA | mA | pF |
| TPN3021 | 4 | 28 | 38 | 300 | 30 | 16 |

1. See Figure 1: Test circuit 1 for I_{BO} and V_{BO} parameters

2. See Figure 2: Test circuit 2 for I_H parameter

3. $V_R = 0 V \text{ bias}, V_{RMS} = 1 V, F = 1 MHz$



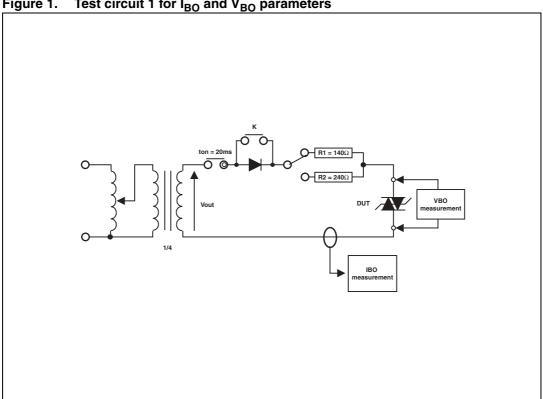
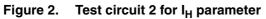
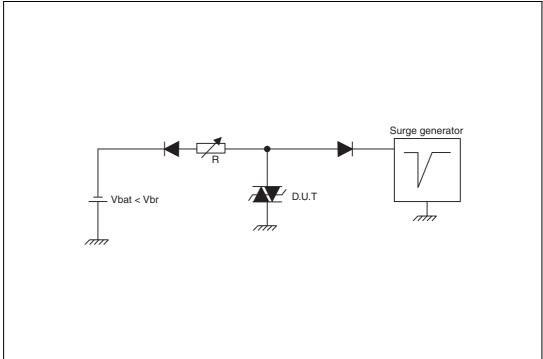


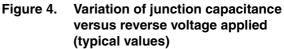
Figure 1. Test circuit 1 for I_{BO} and V_{BO} parameters

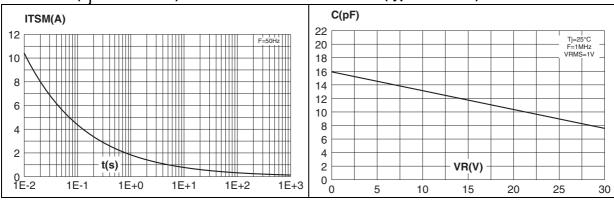




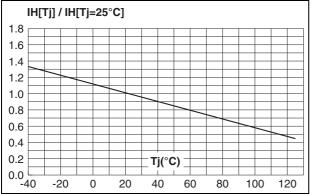
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Figure 3. Non repetitive surge peak on-state current versus overload duration $(T_i \text{ initial} = 25^{\circ}\text{C})$

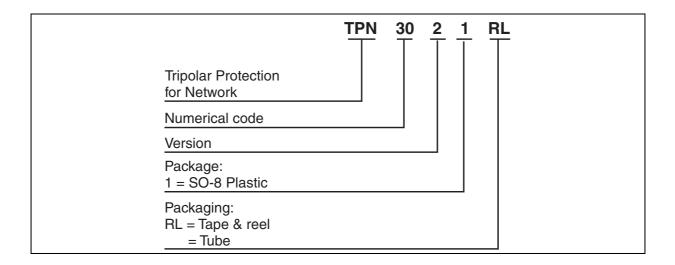








2 Ordering information scheme





3 Package mechanical data

| | | | | DIMEN | ISIONS | | |
|---|------|------|----------|-------|--------|--------|-------|
| | REF. | Mi | illimetr | es | | Inches | |
| | | Min. | Тур. | Max. | Min. | Тур. | Max. |
| | А | | | 1.75 | | | 0.069 |
| | a1 | 0.1 | | 0.25 | 0.004 | | 0.010 |
| | a2 | | | 1.65 | | | 0.065 |
| | b | 0.35 | | 0.48 | 0.014 | | 0.019 |
| | b1 | 0.19 | | 0.25 | 0.007 | | 0.010 |
| | С | 0.50 | | | | 0.020 | |
| | c1 | | | 45° | (typ) | | |
| | D | 4.8 | | 5.0 | 0.189 | | 0.197 |
| F | E | 5.8 | | 6.2 | 0.228 | | 0.244 |
| | е | | 1.27 | | | 0.050 | |
| | e3 | | 3.81 | | | 0.150 | |
| | F | 3.8 | | 4.0 | 0.15 | | 0.157 |
| | L | 0.4 | | 1.27 | 0.016 | | 0.050 |
| | М | | | 0.6 | | | 0.024 |
| | S | | | 8° (1 | max) | | |

Table 6.SO-8 (Plastic) dimensions

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.



4 Ordering information

| Part number | Marking | Package | Weight | Base qty | Delivery mode |
|---------------------------------|---------|----------|--------|----------|---------------|
| TPN3021 | TPN302 | <u> </u> | 0.08 g | 100 | Tube |
| TPN3021RL ⁽¹⁾ | TPN302 | SO-8 | 0.00 Y | 2500 | Tape and reel |

1. Preferred device

5 Revision history

| Date | Revision | Changes |
|-------------|----------|--|
| Sep 2001 | 3 | Previous release. |
| 07-Feb-2006 | 4 | Reformatted to current template. Maximum junction temperature parameter replaced by Operating junction temperature range in Table 3. Added footnote 1 to Ordering information table |



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